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MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

Bias Resistor Transistors

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-70/SOT-323 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel – Use the Device Number to order the 7 inch/3000 unit reel. Replace “T1” with “T3” in the Device Number to order the 13 inch/10,000 unit reel.
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current	I _C	100	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

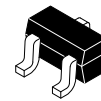
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



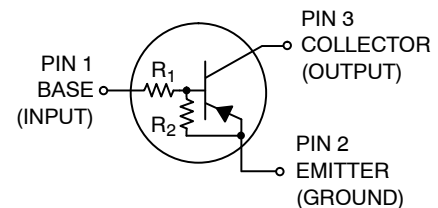
ON Semiconductor®

<http://onsemi.com>

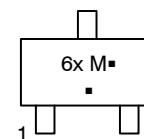
PNP SILICON BIAS RESISTOR TRANSISTORS



SC-70/SOT-323
CASE 419
STYLE 3



MARKING DIAGRAM



- 6x = Device Code
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See specific ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	202 (Note 1) 310 (Note 2) 1.6 (Note 1) 2.5 (Note 2)	mW $^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	618 (Note 1) 403 (Note 2)	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	280 (Note 1) 332 (Note 2)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

- FR-4 @ Minimum Pad
- FR-4 @ 1.0 x 1.0 inch Pad

ORDERING INFORMATION AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping†
MUN5111T1G, SMUN5111T1G	SC-70/SOT-323 (Pb-Free)	6A	10	10	3,000/Tape & Reel
MUN5112T1G, SMUN5112T1G	SC-70/SOT-323 (Pb-Free)	6B	22	22	3,000/Tape & Reel
MUN5113T1G, SMUN5113T1G	SC-70/SOT-323 (Pb-Free)	6C	47	47	3,000/Tape & Reel
MUN5113T3G	SC-70/SOT-323 (Pb-Free)	6C	47	47	10,000/Tape & Reel
MUN5113T1G	SC-70/SOT-323 (Pb-Free)	6C	47	47	3,000/Tape & Reel
MUN5114T1G, SMUN5114T1G	SC-70/SOT-323 (Pb-Free)	6D	10	47	3,000/Tape & Reel
MUN5115T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6E	10	∞	3,000/Tape & Reel
MUN5116T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6F	4.7	∞	3,000/Tape & Reel
MUN5130T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6G	1.0	1.0	3,000/Tape & Reel
MUN5131T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6H	2.2	2.2	3,000/Tape & Reel
MUN5132T1G, NSVMUN5132T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6J	4.7	4.7	3,000/Tape & Reel
MUN5133T1G, SMUN5133T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6K	4.7	47	3,000/Tape & Reel
MUN5134T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6L	22	47	3,000/Tape & Reel
MUN5135T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	6M	2.2	47	3,000/Tape & Reel
MUN5136T1G	SC-70/SOT-323 (Pb-Free)	6N	100	100	3,000/Tape & Reel
MUN5137T1G	SC-70/SOT-323 (Pb-Free)	6P	47	22	3,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

- New devices. Updated curves to follow in subsequent data sheets.

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Cutoff Current (V _{CB} = 50 V, I _E = 0)	I _{CBO}	-	-	100	nAdc
Collector-Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0)	I _{CEO}	-	-	500	nAdc
Emitter-Base Cutoff Current (V _{EB} = 6.0 V, I _C = 0)	I _{EBO}				mAdc
MUN5111T1, SMUN5111T1		-	-	0.5	
MUN5112T1, SMUN5112T1		-	-	0.2	
MUN5113T1, SMUN5113T1		-	-	0.1	
MUN5114T1, SMUN5114T1		-	-	0.2	
MUN5115T1		-	-	0.9	
MUN5116T1		-	-	1.9	
MUN5130T1		-	-	4.3	
MUN5131T1		-	-	2.3	
MUN5132T1, NSVMUN5132T1		-	-	1.5	
MUN5133T1, SMUN5133T1		-	-	0.18	
MUN5134T1		-	-	0.13	
MUN5135T1		-	-	0.2	
MUN5136T1		-	-	0.05	
MUN5137T1		-	-	0.13	
Collector-Base Breakdown Voltage (I _C = 10 μA, I _E = 0)	V _{(BR)CBO}	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 4) (I _C = 2.0 mA, I _B = 0)	V _{(BR)CEO}	50	-	-	Vdc

ON CHARACTERISTICS (Note 4)

DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA)	h _{FE}				
MUN5111T1, SMUN5111T1		35	60	-	
MUN5112T1, SMUN5112T1		60	100	-	
MUN5113T1, SMUN5113T1		80	140	-	
MUN5114T1, SMUN5114T1		80	140	-	
MUN5115T1		160	250	-	
MUN5116T1		160	250	-	
MUN5130T1		3.0	5.0	-	
MUN5131T1		8.0	15	-	
MUN5132T1, NSVMUN5132T1		15	27	-	
MUN5133T1, SMUN5133T1		80	140	-	
MUN5134T1		80	130	-	
MUN5135T1		80	140	-	
MUN5136T1		80	150	-	
MUN5137T1		80	140	-	
Collector-Emitter Saturation Voltage (I _C = 10 mA, I _E = 0.3 mA)	V _{CE(sat)}				Vdc
MUN5130T1/MUN5131T1		-	-	0.25	
(I _C = 10 mA, I _B = 5 mA)					
(I _C = 10 mA, I _B = 1 mA)					
MUN5115T1/MUN5116T1/MUN5132T1/NSVMUN5132T1/ MUN5133T1/SMUN5133T1/MUN5134T1		-	-	0.25	
Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 kΩ)	V _{OL}				Vdc
MUN5111T1, SMUN5111T1		-	-	0.2	
MUN5112T1, SMUN5112T1		-	-	0.2	
MUN5114T1, SMUN5114T1		-	-	0.2	
MUN5115T1		-	-	0.2	
MUN5116T1		-	-	0.2	
MUN5130T1		-	-	0.2	
MUN5131T1		-	-	0.2	
MUN5132T1, NSVMUN5132T1		-	-	0.2	
MUN5133T1, SMUN5133T1		-	-	0.2	
MUN5134T1		-	-	0.2	
MUN5135T1		-	-	0.2	
(V _{CC} = 5.0 V, V _B = 3.5 V, R _L = 1.0 kΩ)					
MUN5113T1		-	-	0.2	
(V _{CC} = 5.0 V, V _B = 5.5 V, R _L = 1.0 kΩ)					
MUN5136T1		-	-	0.2	
(V _{CC} = 5.0 V, V _B = 4.0 V, R _L = 1.0 kΩ)					
MUN5137T1		-	-	0.2	

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.050\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN5130T1 ($V_{CC} = 5.0\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1.0\text{ k}\Omega$) MUN5115T1 MUN5116T1 MUN5131T1 MUN5132T1, NSVMUN5132T1	V_{OH}	4.9 4.9 4.9 4.9 4.9	- - - - -	- - - - -	Vdc
Input Resistor MUN5111T1, SMUN5111T1 MUN5112T1, SMUN5112T1 MUN5113T1, SMUN5113T1 MUN5114T1, SMUN5114T1 MUN5115T1 MUN5116T1 MUN5130T1 MUN5131T1 MUN5132T1, NSVMUN5132T1 MUN5133T1, SMUN5133T1 MUN5134T1 MUN5135T1 MUN5136T1 MUN5137T1	R_1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 1.54 70 32.9	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 2.2 100 47	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 2.86 130 61.1	$\text{k}\Omega$
Resistor Ratio MUN5111T1/SMUN5111T1/MUN5112T1/SMUN5112T1/ MUN5113T1/SMUN5113T1/MUN5136T1 MUN5114T1/SMUN5114T1 MUN5115T1/MUN5116T1 MUN5130T1/MUN5131T1/MUN5132T1/NSVMUN5132T1 MUN5133T1/SMUN5133T1 MUN5134T1 MUN5135T1 MUN5136T1 MUN5137T1	R_1/R_2	0.8 0.17 - 0.8 0.055 0.38 0.038 1.7	1.0 0.21 - 1.0 0.1 0.47 0.047 2.1	1.2 0.25 - 1.2 0.185 0.56 0.056 2.6	

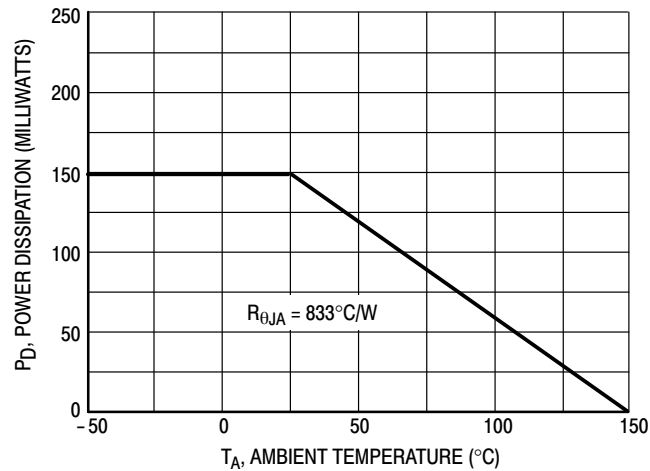


Figure 1. Derating Curve

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5111T1G, SMUN5111T1G

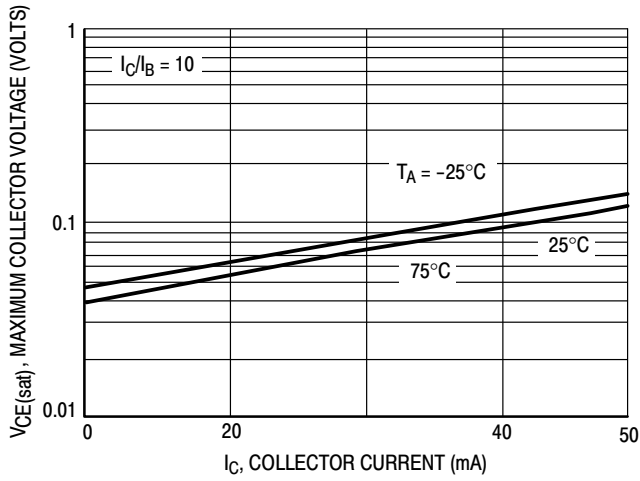


Figure 2. $V_{CE(sat)}$ versus I_C

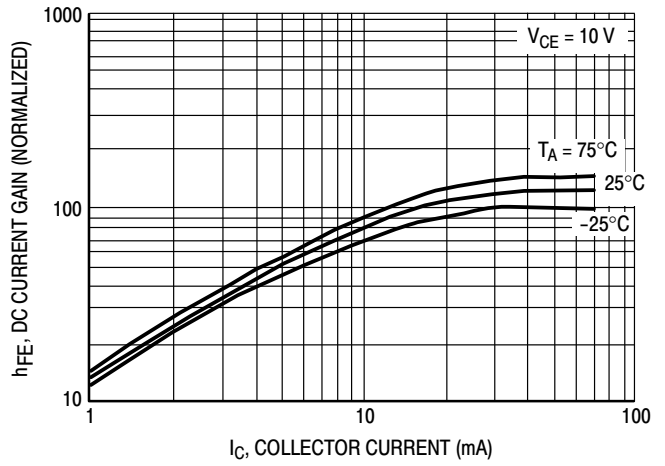


Figure 3. DC Current Gain

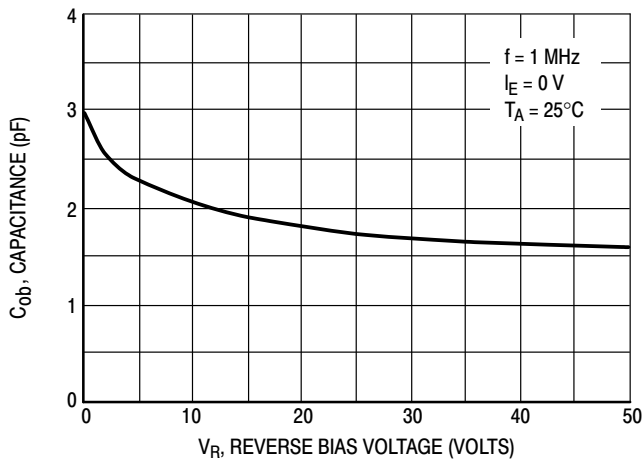


Figure 4. Output Capacitance

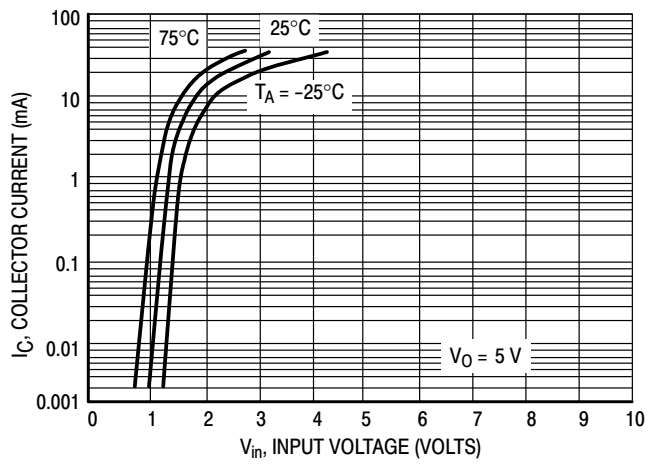


Figure 5. Output Current versus Input Voltage

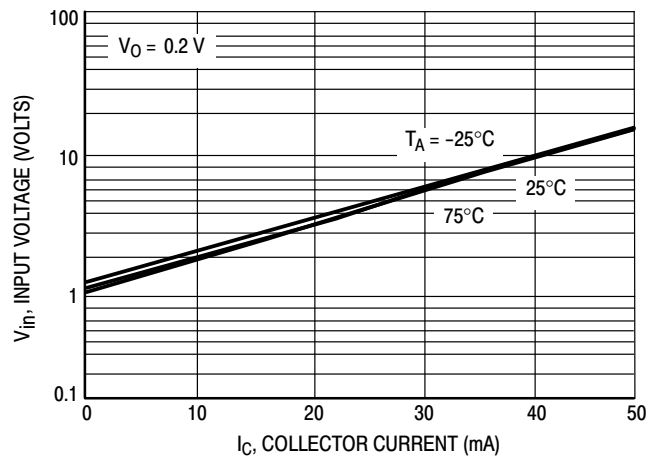


Figure 6. Input Voltage versus Output Current

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5112T1G, SMUN5112T1G

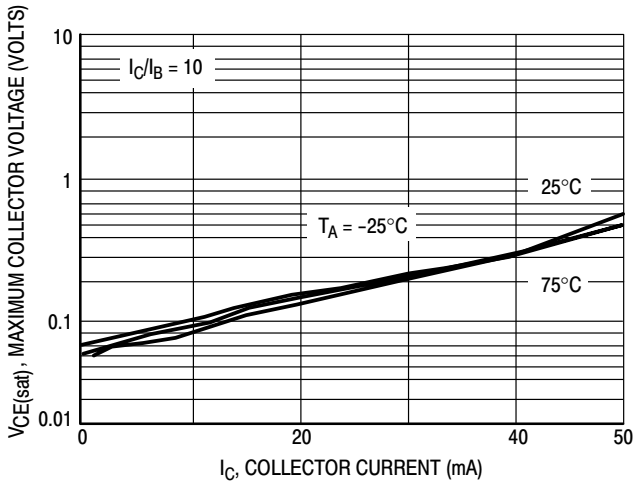


Figure 7. $V_{CE(sat)}$ versus I_C

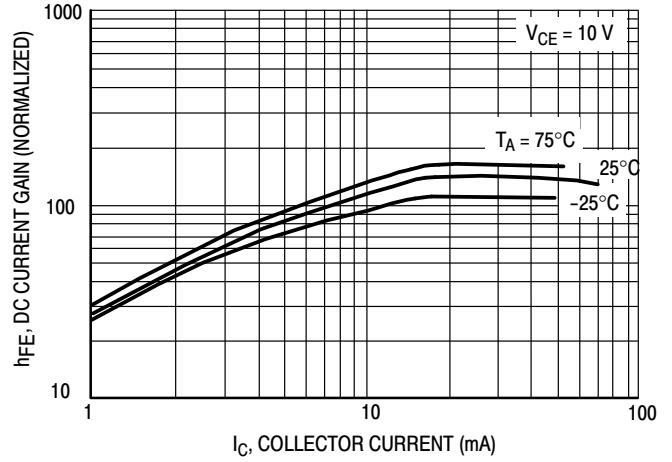


Figure 8. DC Current Gain

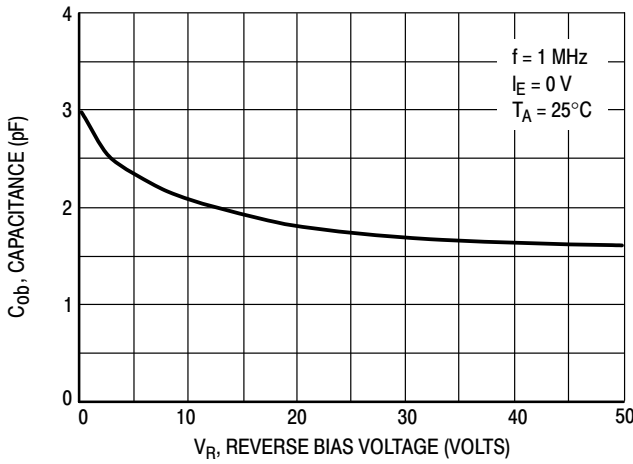


Figure 9. Output Capacitance

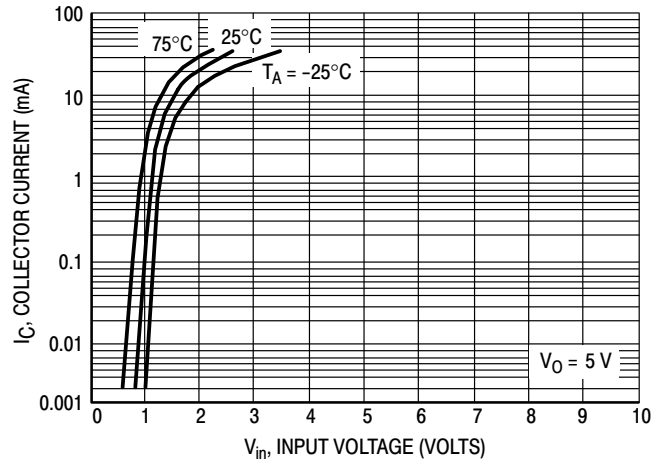


Figure 10. Output Current versus Input Voltage

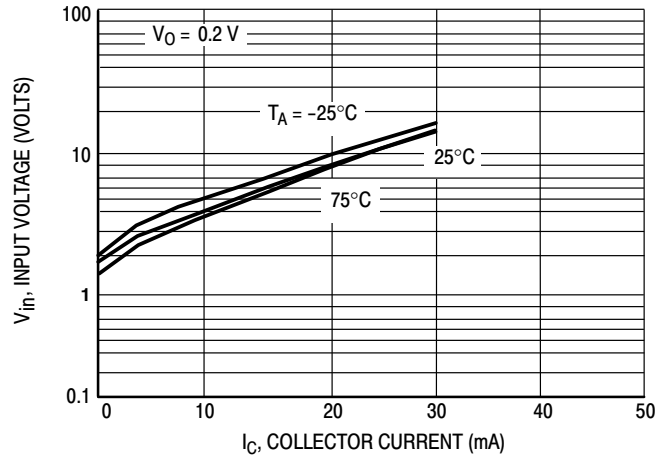


Figure 11. Input Voltage versus Output Current

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5113T1G, SMUN5113T1G

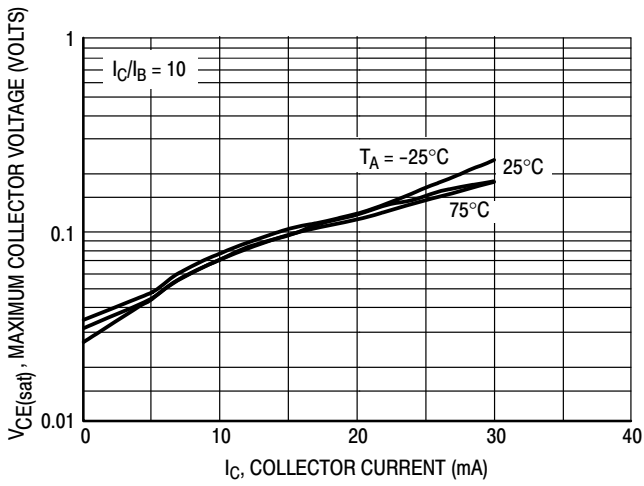


Figure 12. $V_{CE(sat)}$ versus I_C

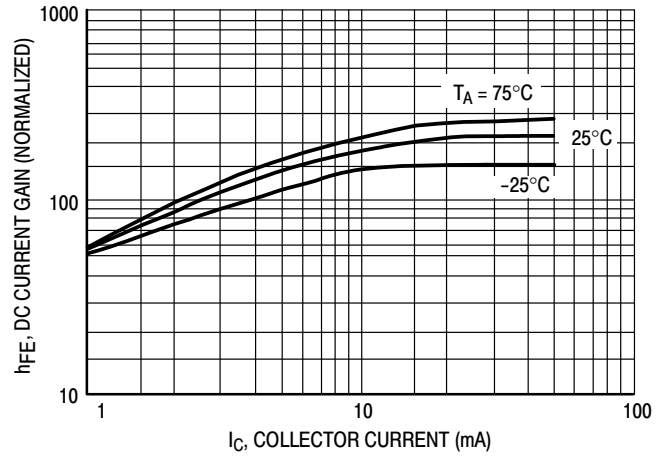


Figure 13. DC Current Gain

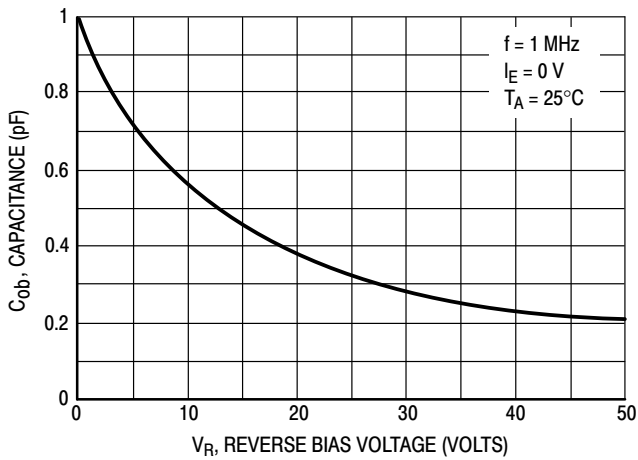


Figure 14. Output Capacitance

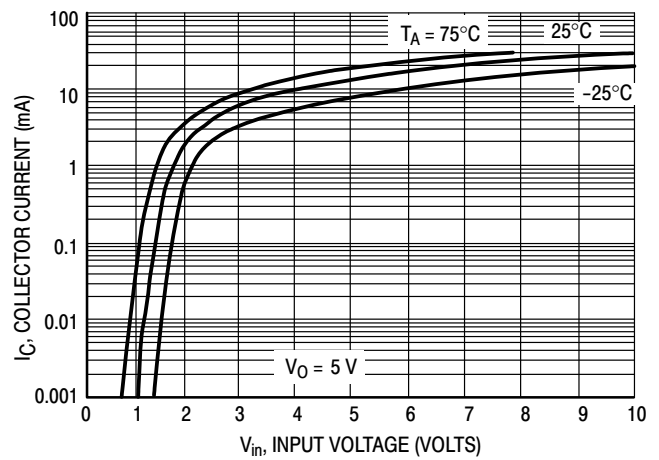


Figure 15. Output Current versus Input Voltage

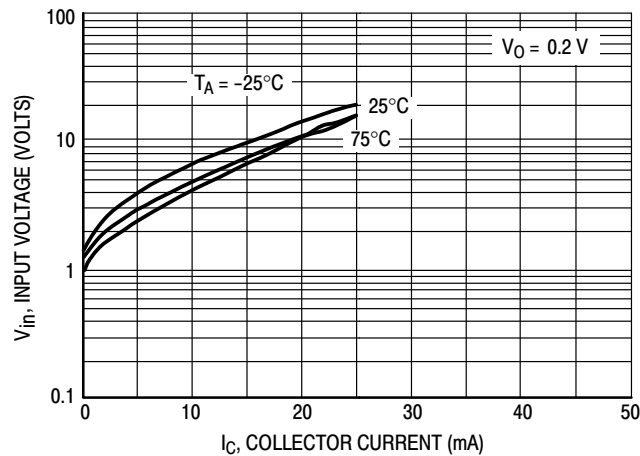


Figure 16. Input Voltage versus Output Current

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5114T1G, SMUN5114T1G

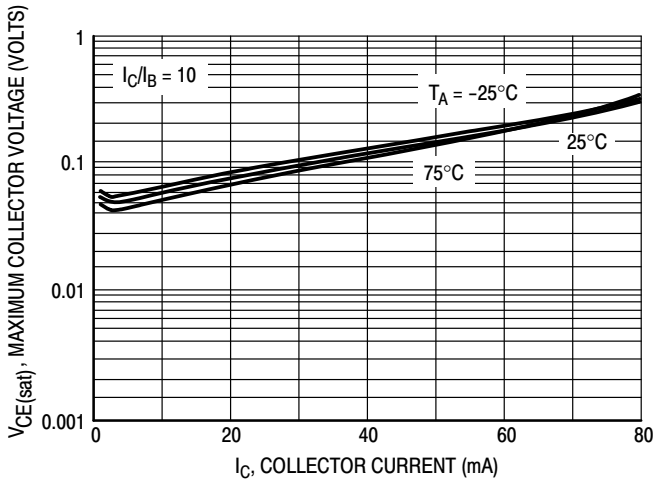


Figure 17. $V_{CE(sat)}$ versus I_C

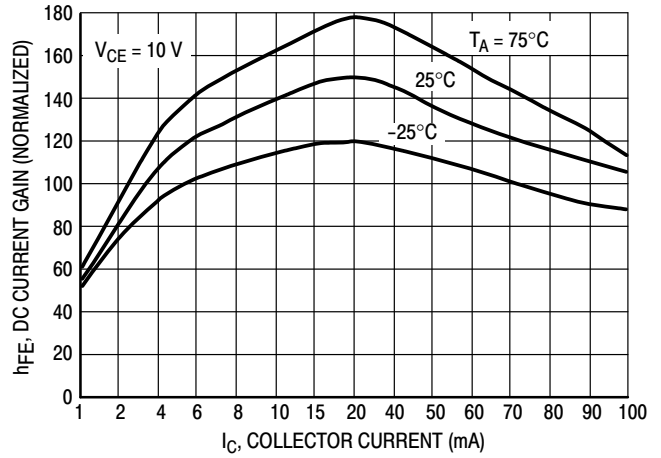


Figure 18. DC Current Gain

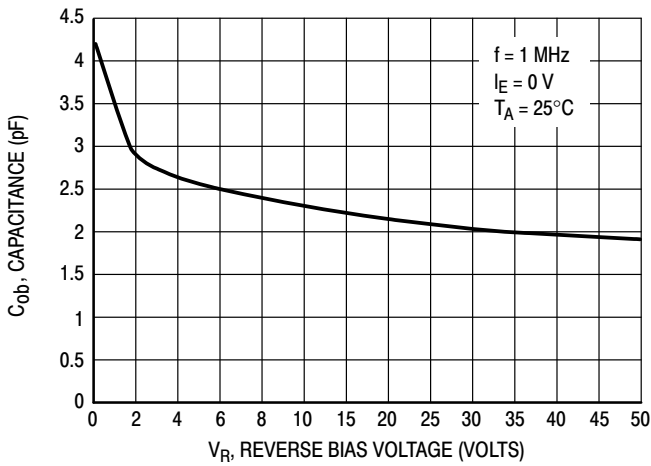


Figure 19. Output Capacitance

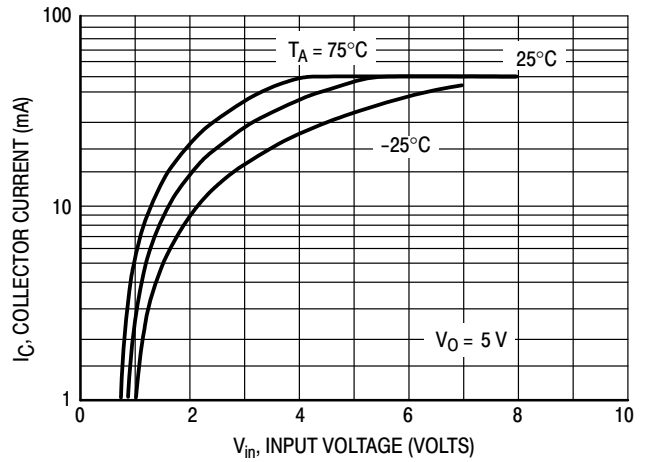


Figure 20. Output Current versus Input Voltage

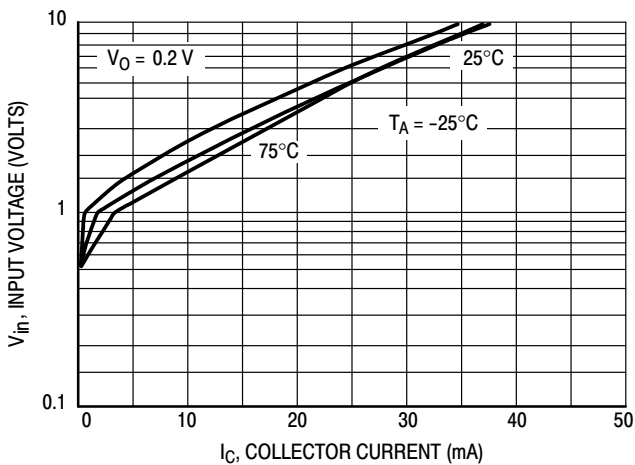


Figure 21. Input Voltage versus Output Current

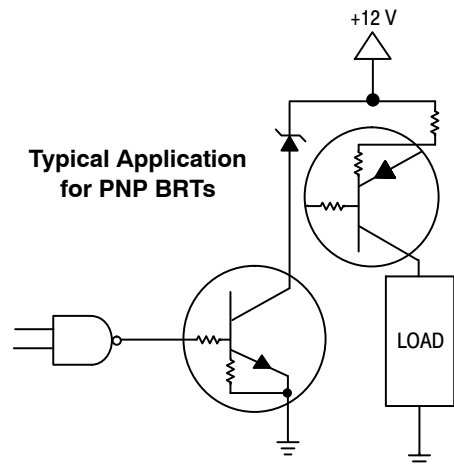


Figure 22. Inexpensive, Unregulated Current Source

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5132T1G, NSVMUN5132T1G

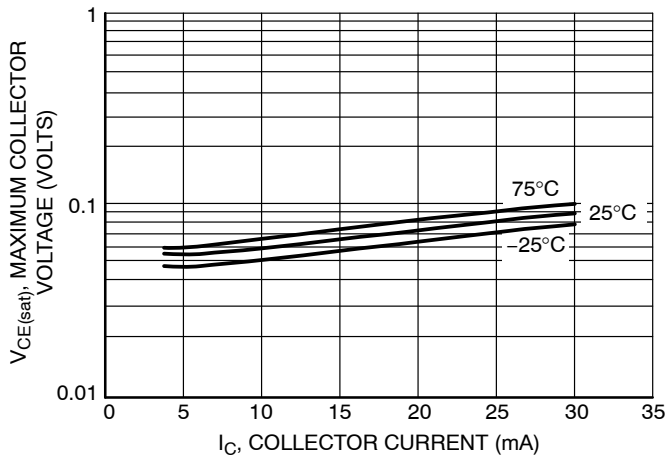


Figure 23. Maximum Collector Voltage versus Collector Current

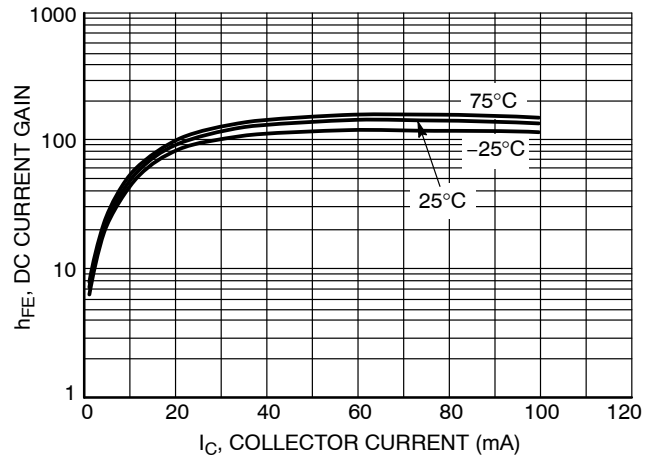


Figure 24. DC Current Gain

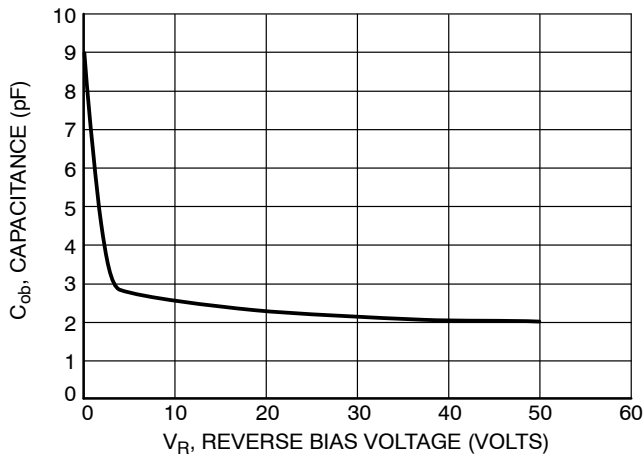


Figure 25. Output Capacitance

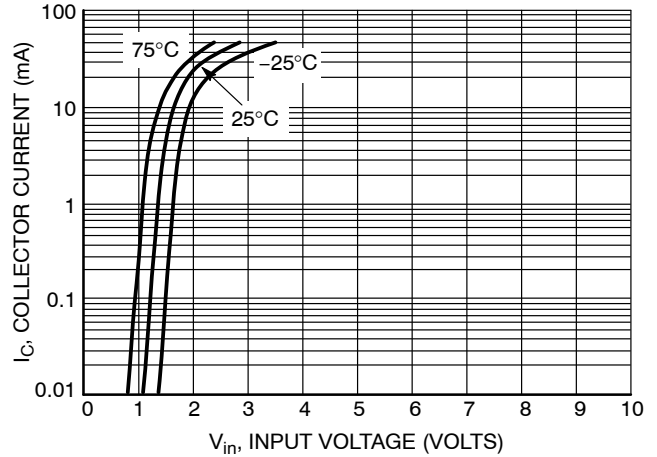


Figure 26. Output Current versus Input Voltage

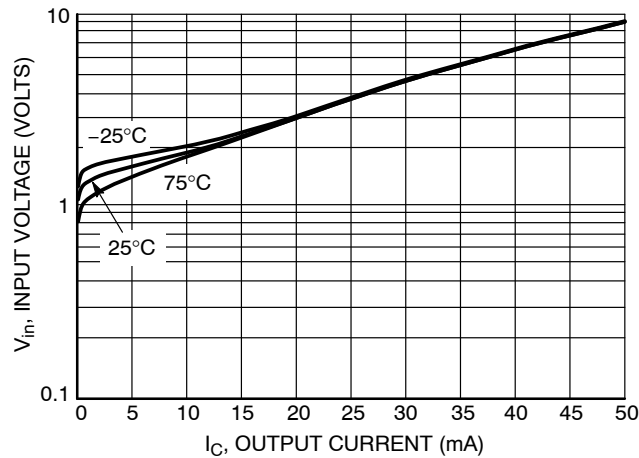


Figure 27. Input Voltage versus Output Current

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5133T1G, SMUN5133T1G

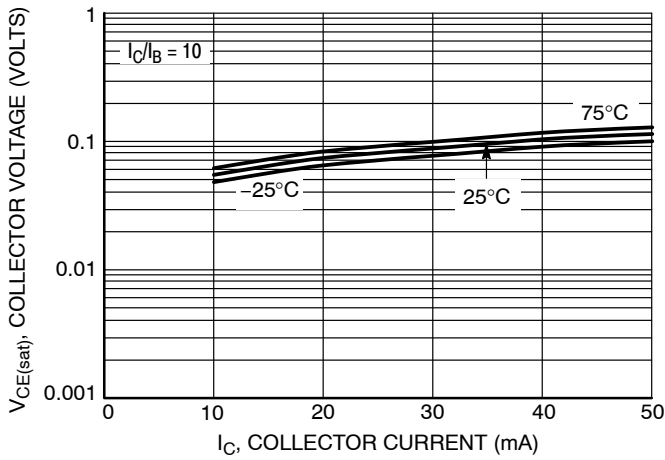


Figure 28. $V_{CE(sat)}$ versus I_C

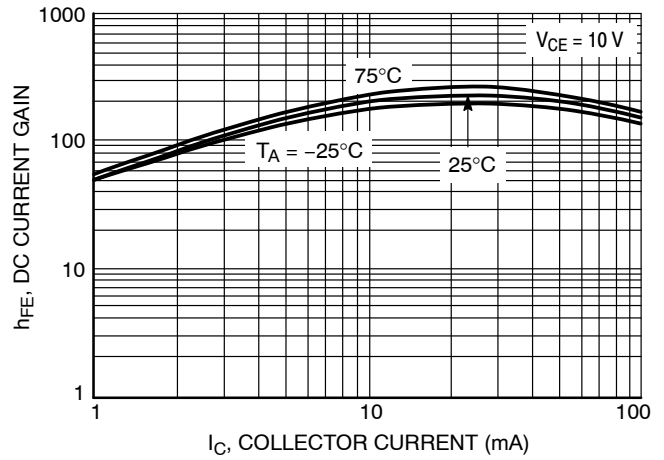


Figure 29. DC Current Gain

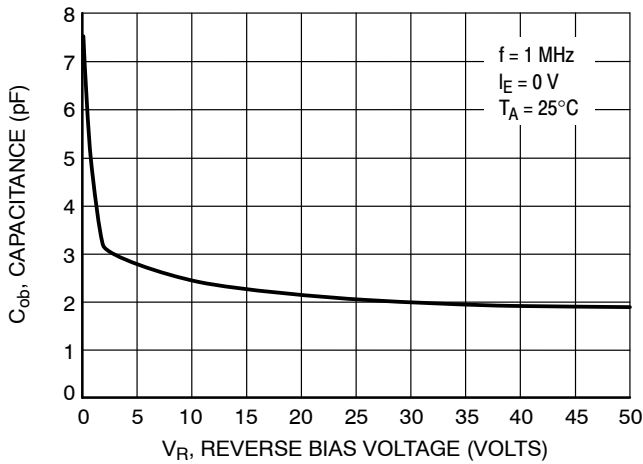


Figure 30. Output Capacitance

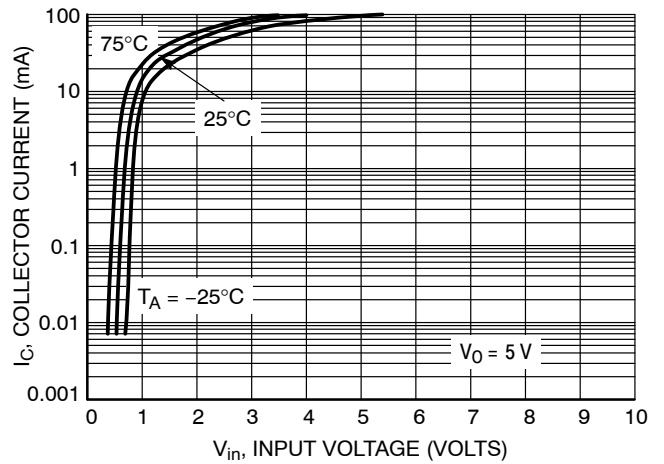


Figure 31. Output Current versus Input Voltage

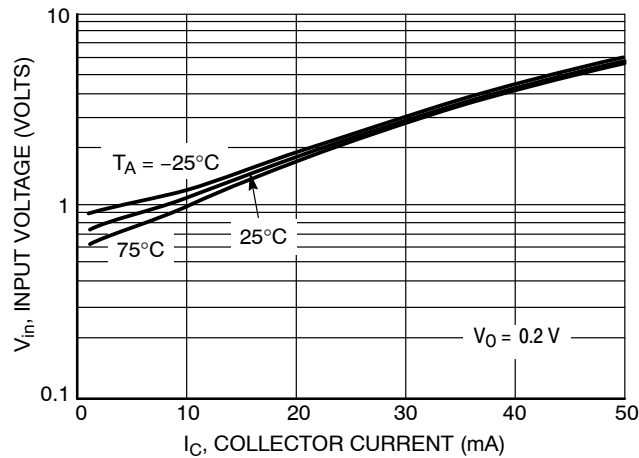


Figure 32. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5135T1G

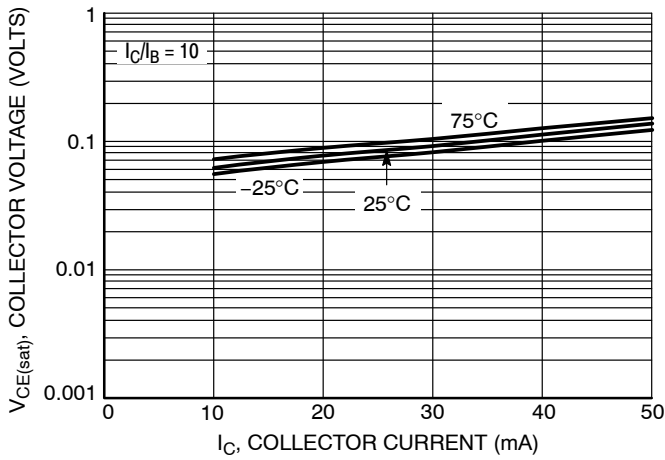


Figure 33. $V_{CE(sat)}$ versus I_C

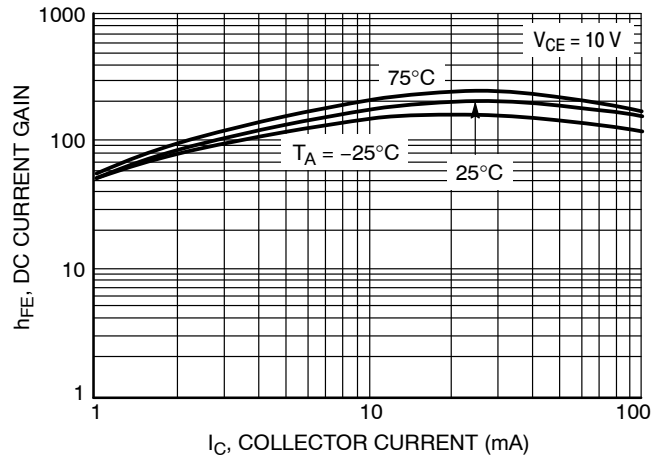


Figure 34. DC Current Gain

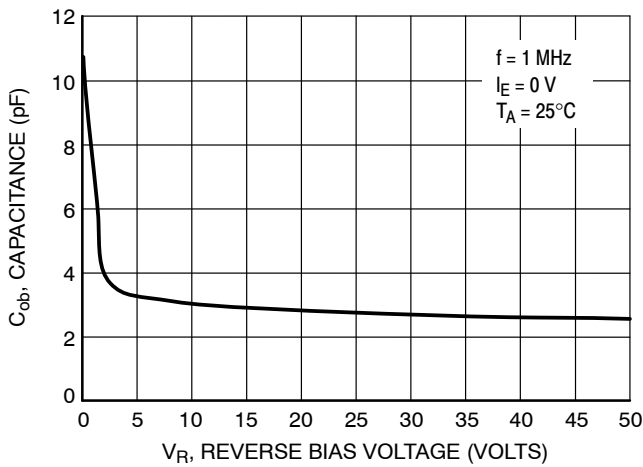


Figure 35. Output Capacitance

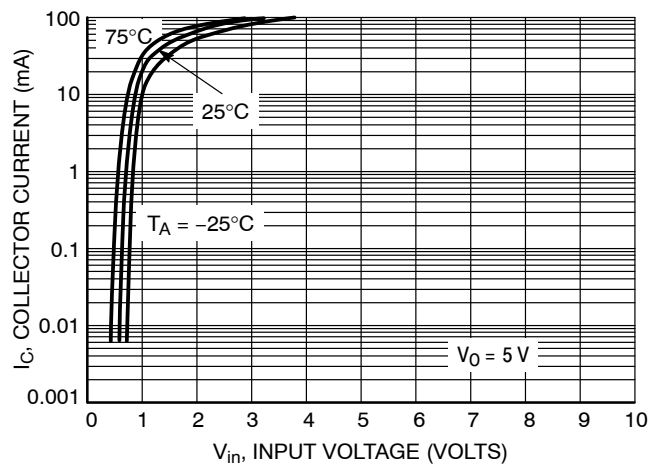


Figure 36. Output Current versus Input Voltage

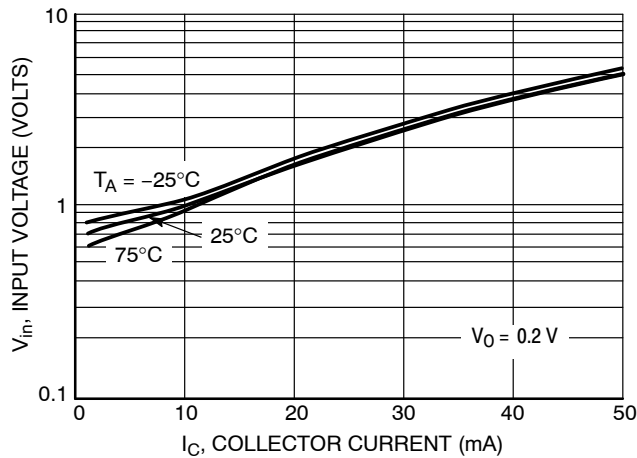


Figure 37. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5136T1G

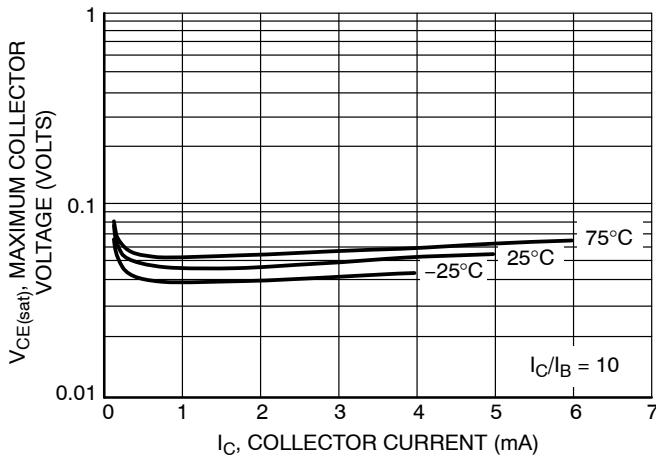


Figure 38. Maximum Collector Voltage versus Collector Current

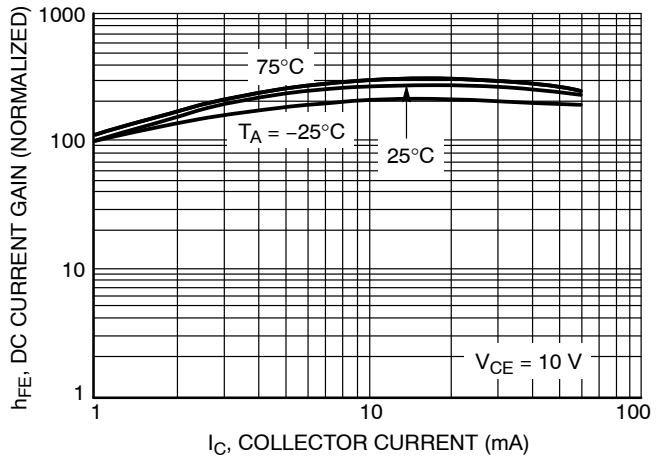


Figure 39. DC Current Gain

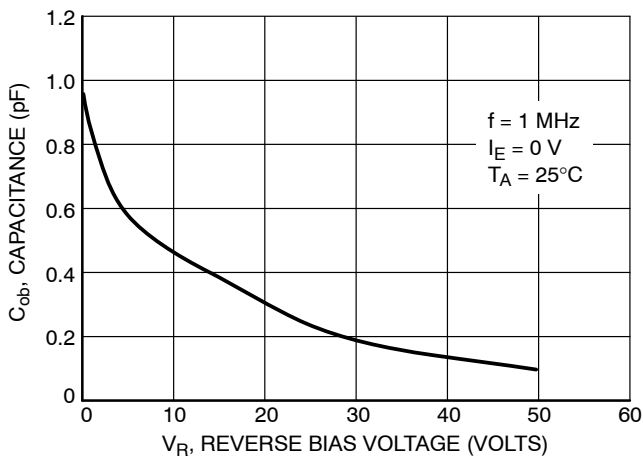


Figure 40. Output Capacitance

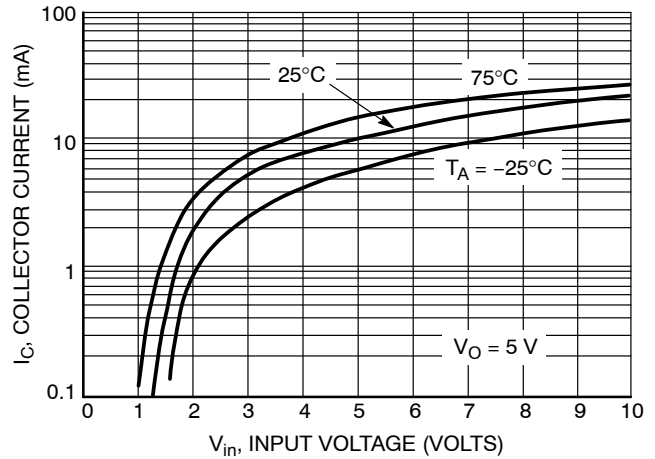


Figure 41. Output Current versus Input Voltage

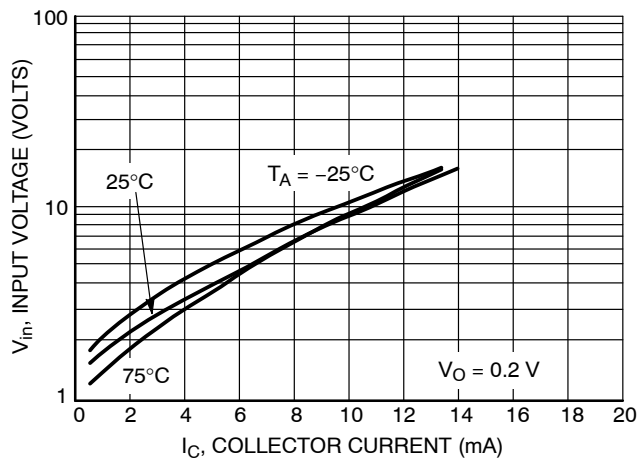


Figure 42. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS — MUN5137T1G

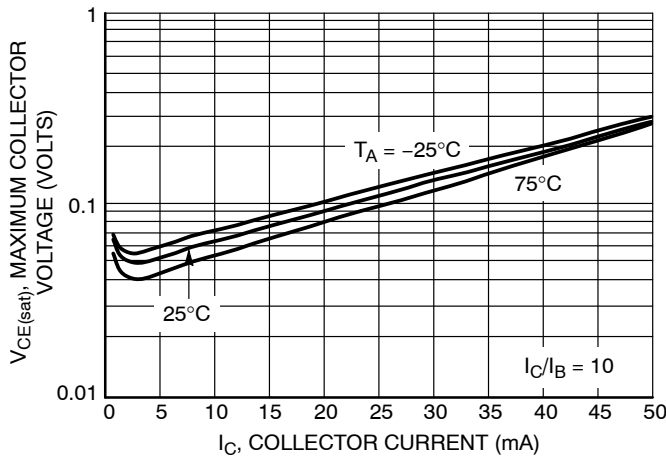


Figure 43. Maximum Collector Voltage versus Collector Current

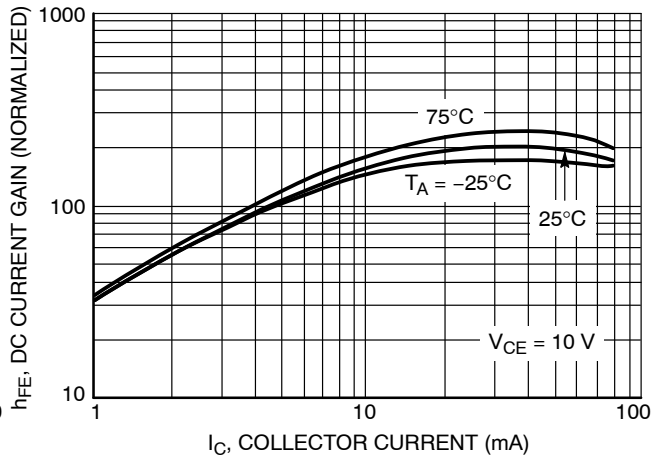


Figure 44. DC Current Gain

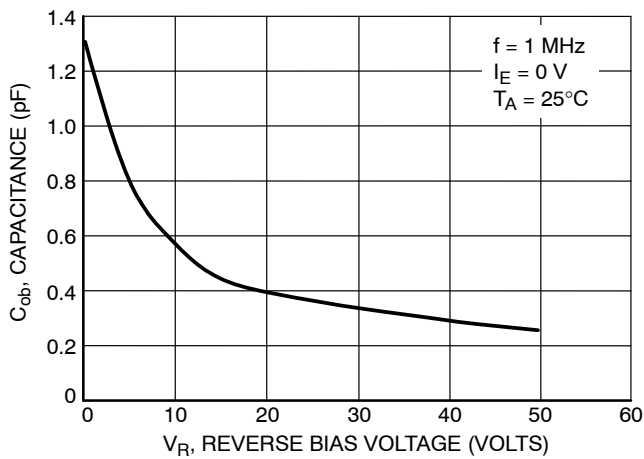


Figure 45. Output Capacitance

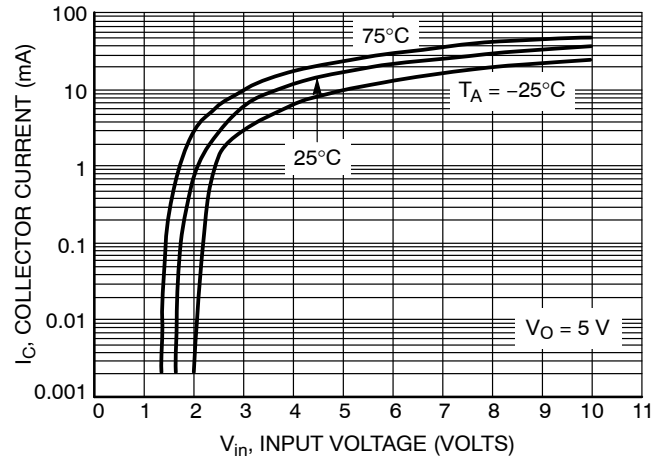


Figure 46. Output Current versus Input Voltage

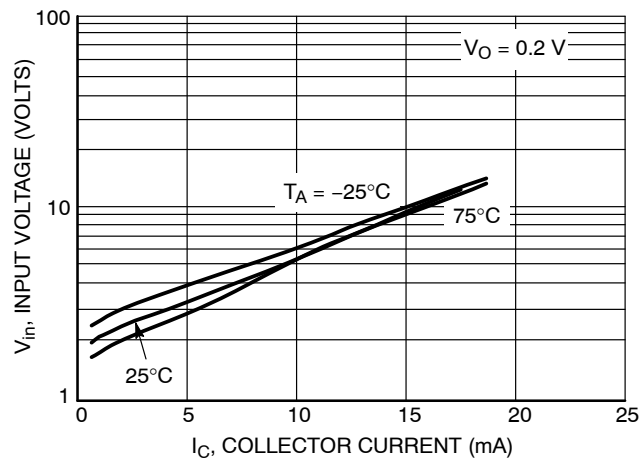
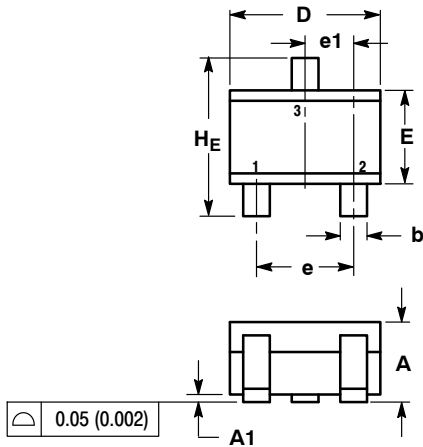


Figure 47. Input Voltage versus Output Current

MUN5111T1 Series, SMUN5111T1, NSVMUN5111T1 Series

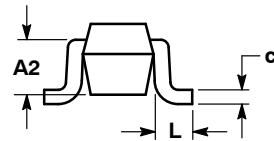
PACKAGE DIMENSIONS

SC-70/SOT-323
CASE 419-04
ISSUE N



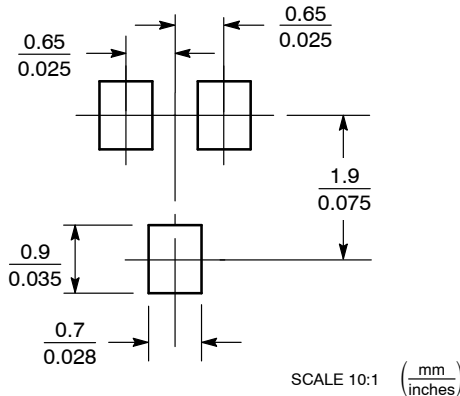
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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